

# Al-Nb-Si-Ti (Aluminum-Niobium-Silicon-Titanium)

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The information on this quaternary system is limited to the experimental results of [2004Ant] in Ti-rich quaternary alloys with low Nb contents (up to 5 at.%). The experimental data were used to derive the binary and ternary interaction parameters. The vertical sections and an isothermal section at 800 °C computed by [2004Ant] are not quite in agreement with their own experimental data.

## Binary Systems

For brief descriptions of the Al-Nb, Al-Ti, and Nb-Ti systems, see the Al-Nb-Ti update by [2005Rag]. For Al-Si and Si-Ti descriptions, see the Al-Si-Ti update in this issue. The Nb-Si phase diagram [Massalski2] has the following intermediate phases: Nb<sub>3</sub>Si (Ti<sub>3</sub>P-type tetragonal) stable between 1980 and 1770 °C, βNb<sub>5</sub>Si<sub>3</sub> (D8<sub>m</sub>, W<sub>5</sub>Si<sub>3</sub>-type tetragonal), αNb<sub>5</sub>Si<sub>3</sub> (D8<sub>r</sub>, Cr<sub>5</sub>B<sub>3</sub>-type tetragonal), and NbSi<sub>2</sub> (C40, CrSi<sub>2</sub>-type hexagonal).

## Ternary Systems

For an update of the Al-Nb-Ti system, see [2005Rag]. An update of the Al-Si-Ti system appears in this issue. A thermodynamic assessment of the Al-Nb-Si system was reported by [2004Sha]. Two isothermal sections at 1400 and 1000 °C were computed by [2004Sha] and were found to be in good agreement with the published experimental data. At both these temperatures, a ternary phase with the C54, αTiSi<sub>2</sub>-type orthorhombic structure is stable and has a small homogeneity range along the isoconcentrate line of 33.3 at.% Nb. A computed liquidus projection was also given by [2004Sha]. Recent investigations of the Nb-Si-Ti system have reported isothermal sections at 1200, 1150, and 1000 °C [2004Zha] and at 1200 and 1100 °C [2002Wan].

## Quaternary Phase Equilibria

With starting metals of 99.995% Al, 99.86% Nb, 99.999% Si, and 99.98% Ti, [2004Ant] arc-melted under Ar atm eight quaternary alloys with 2.5, 3.5, or 5 at.% Nb, with Al and Si contents up to 30 and 6.5 at.%, respectively. Low Nb contents were chosen, so that no Ti<sub>2</sub>NbAl (O phase) forms in the “in-situ” composite microstructure of (βTi) + Ti<sub>5</sub>Si<sub>3</sub> of the as-cast alloys. The phase equilibria were studied with scanning and transmission electron microscopy, x-ray diffraction, and electron probe microanalysis. Differential thermal analysis was carried out at a heating/cooling rate of 10 °C per min. In alloys annealed at 800 °C, the following phases were identified: (βTi), (αTi), α<sub>2</sub> (Ti<sub>3</sub>Al), Ti<sub>5</sub>Si<sub>3</sub> (denoted z by [2004Ant]), and Ti<sub>3</sub>Si (denoted η by [2004Ant]). Ti<sub>3</sub>Si (η) was found to have a composition range of (Ti<sub>1-x</sub>Nb<sub>x</sub>)<sub>3</sub>(Si<sub>1-y</sub>Al<sub>y</sub>) (0.05 ≤ x ≤ 0.07 and 0.001 ≤ y ≤ 0.02). It was confirmed to have the Ti<sub>3</sub>P-type tetrag-

onal structure [2004Ant]. The solubility of Nb in Ti<sub>3</sub>Si is significant, but that of Al is more limited. The morphology observed in the microstructure suggested its formation through a peritectoid reaction as in the Ti-Si system: (βTi) + Ti<sub>5</sub>Si<sub>3</sub> → Ti<sub>3</sub>Si. Ti<sub>5</sub>Si<sub>3</sub> (z) found to have a composition range of (Ti<sub>1-x</sub>Nb<sub>x</sub>)<sub>5</sub>(Si<sub>1-y</sub>Al<sub>y</sub>)<sub>3</sub> (0.01 ≤ x ≤ 0.05 and 0.07 ≤ y ≤ 0.788) [2004Ant].

Using a subregular solution model, [2004Ant] computed the quaternary phase equilibria and presented two vertical sections at a constant content (at.%) of 5Si-3.5Nb and 5Al-6.5Si, respectively. An isothermal section at 800 °C was also computed at a constant content of 3.5Nb. Further, a vertical section between 10-30 at.% Al at a constant content of 5Si-3.5Nb was presented, that “combines the experimental data (at 800 °C) and calculated points” [2004Ant]. The agreement between the computed and experimental phase fields is only partial in the diagrams presented by [2004Ant]. Clearly, there is a need to examine the problem further. The qualitative conclusions of [2004Ant] are as follows: Nb stabilizes Ti<sub>3</sub>Si at zero or low concentrations of Al. Beyond 10 at.% Al, the stabilizing effect of Nb on Ti<sub>3</sub>Si appears to be neutralized by Al, and this phase is not stable at 800 °C. See also the discussion in [Massalski2] on the stability of Ti<sub>3</sub>Si in the Si-Ti binary system.

[1991Che] made three quaternary alloys with Nb additions of 5, 10, and 15 at.%, respectively (substituted by Ti) to a hypoeutectic Ti-Al-Si alloy with the composition Ti-23.5Al-6.5Si (at.%). The microstructure of the as-cast hypoeutectic alloy consisted of primary α<sub>2</sub> in a eutectic mixture of (α<sub>2</sub> + Ti<sub>5</sub>Si<sub>3</sub>). With the addition of 10 and 15 at.% Nb, the microstructure consisted of the primary α<sub>2</sub>, the eutectic mixture, (βTi), and the O phase (Ti<sub>2</sub>NbAl). Heat treatment at temperatures between 1100 and 850 °C resulted in changes such as the ordering of the body-centered cubic (bcc) phase and precipitation of Ti<sub>5</sub>Si<sub>3</sub>. No phase relationships were determined.

## References

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